



#### 4-Bit Bi-directional Level Shifter for open-drain and Push-Pull Application Description

The PI4ULS3V204 is a 4-bit configurable dual

supply bidirectional auto sensing translator that does

not require a directional control pin. The A and B ports

are designed to track two different power supply rails,

VCCA and VCCB respectively. Both the VCCA and

VCCB supply rails are configurable from 1.1V to 3.6V.

This allows voltage logic signals on the VCCA side to

be translated into lower, higher or equal value voltage

resistors on the I/O lines. The integrated pull-up

resistors are used to pull-up the I/O lines to either V<sub>CCA</sub>

or V<sub>CCB</sub>. The PI4ULS3V204 is an excellent match for

open-drain applications such as the I<sup>2</sup>C communication

The translator has integrated 10 k $\Omega$  pull-up

logic signals on the VCCB side, and vice-versa.

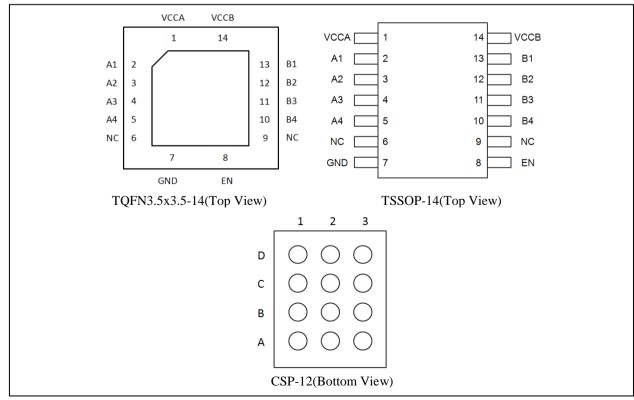
Features

- +  $V_{CCA}$  can be Less than, Greater than or Equal to  $V_{CCB}$
- 1.1V to 3.6V on A Port and 1.1V to 3.6V on B Port
- High-Speed with 24 Mb/s Data Rate for push-pull application
- High-Speed with 2 Mb/s Data Rate for open-drain application
- No Direction-Control Signal Needed
- Low Bit-to-Bit Skew
- Non-preferential Power-up Sequencing
- ESD protection exceeds 8000V HBM per JESD22-A114
- Integrated 10 kΩ Pull-up Resistors
- Package: TSSOP-14,TQFN3.5x3.5-14,CSP-12

# Applications

- I<sup>2</sup>C, SMBus, MDIO
- Low Voltage ASIC Level Translation
- Mobile Phones, PDAs, Camera

## **Pin Configuration**



bus.





# **Block Diagram**

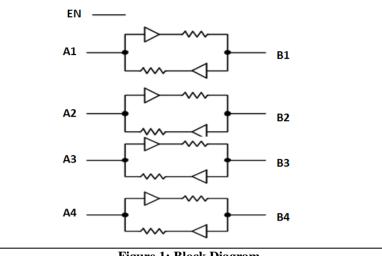


Figure 1: Block Diagram

# **Maximum Ratings**

Storage Temperature	$-65^{\circ}$ C to $+150^{\circ}$ C
DC Supply Voltage port B	-0.3V to +5.5V
DC Supply Voltage port A	-0.3V to+5.5V
Vi(A) referenced DC Input / Output Voltage	-0.3V to +5.5V
Vi(B) referenced DC Input / Output Voltage	-0.3V to+5.5V
Enable Control Pin DC Input Voltage	0.3V to+5.5V
Short circuit duration (I/O to GND)	40mA

## Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# **Pin Description**

Pin No TSSOP	Pin No TQFN	Pin No CSP	Pin Name	Туре	Description
1	1	B2	V <sub>CCA</sub>	Power	A-port supply voltage. $1.1V \le V_{CCA} \le 3.6 V$
2	2	A3	A1	I/O	Input/output A. Referenced to V <sub>CCA</sub> .
3	3	B3	A2	I/O	Input/output A. Referenced to V <sub>CCA</sub>
4	4	C3	A3	I/O	Input/output A. Referenced to V <sub>CCA</sub>
5	5	D3	A4	I/O	Input/output A. Referenced to V <sub>CCA</sub>
7	7	D2	GND	GND	Ground.
8	8	C2	EN	Input	Output enable (active High). Pull EN low to place all outputs in 3-state mode.
10	10	D1	B4	I/O	Input/output B. Referenced to V <sub>CCB</sub>
11	11	C1	B3	I/O	Input/output B. Referenced to V <sub>CCB</sub>
12	12	B1	B2	I/O	Input/output B. Referenced to V <sub>CCB</sub>
13	13	A1	B1	I/O	Input/output B. Referenced to V <sub>CCB</sub>
14	14	A2	V <sub>CCB</sub>	Power	B-port supply voltage. 1.1 V $\leq V_{CCB} \leq 3.6V$
6, 9	6, 9	/	NC	NC	Not Connect

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## **Recommended operation conditions**

Symbol	Parameter	Min	Тур	Max	Unit
V <sub>CCA</sub>	V <sub>CCA</sub> Positive DC Supply Voltage	1.1	-	3.6	V
V <sub>CCB</sub>	V <sub>CCB</sub> Positive DC Supply Voltage	1.1	-	3.6	V
$V_{\text{EN}}$	Enable Control Pin Voltage	GND	-	3.6	V
V <sub>IO</sub>	I/O Pin Voltage	GND	-	3.6	V
$\Delta t / \Delta V$	Input transition rise or fall time	-	-	10	ns/V
T <sub>A</sub>	Operating Temperature Range	-40	-	+85	C

## **DC Electrical Characteristics**

Unless otherwise specified, -40°C $\leq$ T<sub>A</sub> $\leq$ 85 °C, 1.1V $\leq$ Vcc $\leq$ 3.6V

Symbol	Parameter		Test Conditions	Min	Тур	Max	Unit
		$2.3V \leq V_{CC}$	<sub>(B)</sub> ≤3.6V	$V_{CCB} - 0.4$	-	-	V
V <sub>IHB</sub>	B port Input HIGH Voltage	1.5V≤V <sub>CC</sub>		$V_{CCB} - 0.2$			V
		1.1V≤V <sub>CC</sub>		$V_{CCB} - 0.1$			V
V <sub>ILB</sub>	B port Input LOW Voltage				-	0.15	V
	· · · ·	$2.3V \leq V_{CC}$	<sub>(A)</sub> ≤3.6V	V <sub>CCA</sub> - 0.4			V
V <sub>IHA</sub>	A port Input HIGH Voltage	$1.5V \leq V_{CC}$		V <sub>CCA</sub> - 0.2			V
		$1.1V \leq V_{CC}$	(A) <1.5V	$V_{CCA} - 0.1$			V
V <sub>ILA</sub>	A port Input LOW Voltage	-		-	-	0.15	V
		$1.5V < V_{CC}$	<sub>(A)</sub> ≪3.6V	0.65*V <sub>CCA</sub>	-	-	V
V <sub>IH(EN)</sub>	Control Pin Input HIGH Voltage	$1.1V \leq V_{CC}$		$0.6*V_{CCA}$			V
		$1.5V < V_{CC}$		-	-	0.35* V <sub>CCA</sub>	v
V <sub>IL(EN)</sub>	Control Pin Input LOW Voltage	1.1V≤V <sub>CC</sub>	<sub>(A)</sub> ≤1.5V			0.4* V <sub>CCA</sub>	v
V <sub>OHB</sub>	B port Output HIGH Voltage	B port sour	ce current = $-20 \ \mu A$	0.8*V <sub>CCB</sub>	-	-	V
V <sub>OLB</sub>	B port Output LOW Voltage	B port sink	current =1 mA	-	-	0.4	V
V <sub>OHA</sub>	A port Output HIGH Voltage	A port source current= -20 $\mu$ A		$0.8* V_{CCA}$	-	-	V
V <sub>OLA</sub>	A port Output LOW Voltage	A port sink current =1 mA		-	-	0.4	V
		V <sub>I</sub> = V <sub>CCI</sub> ;	$V_{CC(A)}$ =1.1V to 3.6V, $V_{CC(B)}$ =1.1V to 3.6V	-	1.0	3	μΑ
T		$I_0 = 0A;$	VCCA=1.1V,VCCB=1.8V	-	0.6	2	μΑ
I <sub>CCB</sub>	V <sub>CCB</sub> Supply Current	EN= Low	VCCA=1.8V, VCCB=3.3V	-	0.7	2	μA
		or High	$V_{CC(A)} = 3.6V, V_{CC(B)} = 0V$	-		1	μA
			$V_{CC(A)} = 0V, V_{CC(B)} = 3.6V$	-		1	μA
×		$V_{I} = V_{CCI};$ $I_{O} = 0A;$	$V_{CC(A)}=1.1V$ to 3.6V, $V_{CC(B)}=1.1V$ to 3.6V	-	0.2	1	μΑ
I <sub>CCA</sub>	V <sub>CCA</sub> Supply Current	EN= Low	$V_{CC(A)} = 3.6V, V_{CC(B)} = 0V$	-	-	1	μΑ
		or High	$V_{CC(A)} = 0V, V_{CC(B)} = 3.6V$	-	-	1	μΑ
I <sub>oz</sub>	I/O Tri-state Output Mode Leakage Current	-		-	0.1	1.0	μΑ
I <sub>I-EN</sub>	Control pin leakage Current	$V_{I} = V_{CCI}$ or GND		-	-	1	μA
R <sub>PU</sub>	Pull–Up Resistors I/O A and B	-		-	10	-	kΩ
C <sub>i</sub>	EN	$V_{CC(A)} = 3.3$	$V, V_{CC(B)} = 3.3V$	-	-	0.5	pF
C <sub>iO</sub>	A port		$V, V_{CC(B)} = 3.3V$	-	-	5	pF
	B port		$V, V_{CC(B)} = 3.3V$	-	-	5	pF

Note: All units are production tested at  $T_A = +25$  °C. Limits over the operating temperature range are guaranteed by design.

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## Typical values are for $V_{CCB}$ = +2.8 V, $V_{CCA}$ = +1.8 V and $T_A$ = +25 °C.

# **AC Electrical characteristics**

Timing Characteristics – Rail-to-Rail Driving Configuration (I/O test circuits of Figures 2, 3 and 7, C <sub>LOAD</sub> = 15 pF, driver	
output impedance $\leq 50\Omega$ , $R_{LOAD} = 1 M\Omega$ , $T_A = -40 C$ to 85 C, unless otherwise specified)	

Symbol	Parameter	Test Conditions	Min 7	Гур	Max	Unit
$V_{CCA} = 1.2V \pm 0$	$1.1V$ , $V_{CCB} = 1.8V \pm 0.15V$					-
t <sub>RB</sub>	B port Rise Time	-			20	nS
t <sub>FB</sub>	B port Fall Time	-			25	nS
t <sub>RA</sub>	A port Rise Time	-			20	nS
t <sub>FA</sub>	A port Fall Time	-			20	nS
t <sub>EN</sub>	Enable Time	-			200	nS
t <sub>DIS</sub>	Disable Time	-			200	nS
$t_{\rm PHL-A-B}$	Propagation Delay	-			9	nS
$t_{PLH-A-B}$	(Driving A)	-			11	nS
$t_{\rm PHL-B-A}$	Propagation Delay	-			9	nS
t <sub>PLH-B-A</sub>	(Driving B)	-			10	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps
$V_{CCA} = 1.2V$	$\pm 0.1$ V, V <sub>CCB</sub> = 2.5V $\pm 0.2$ V					
t <sub>RB</sub>	B port Rise Time	-			12	nS
t <sub>FB</sub>	B port Fall Time	-			14	nS
t <sub>RA</sub>	A port Rise Time	-			20	nS
t <sub>FA</sub>	A port Fall Time	-			25	nS
t <sub>EN</sub>	Enable Time	-			200	nS
t <sub>DIS</sub>	Disable Time	-			200	nS
$t_{\rm PHL-A-B}$	Propagation Delay	-			9	nS
$t_{\rm PLH-A-B}$	(Driving A)	-			11	nS
$t_{\rm PHL-B-A}$	Propagation Delay	-			9	nS
t <sub>PLH-B-A</sub>	(Driving B)	-			10	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps
$V_{CCA} = 1.2V_{\Xi}$	$\pm 0.1$ V, V <sub>CCB</sub> = 3.3V $\pm 0.3$ V					
t <sub>RB</sub>	B port Rise Time	-			12	nS
t <sub>FB</sub>	B port Fall Time	-			18	nS
t <sub>RA</sub>	A port Rise Time	-			16	nS
t <sub>FA</sub>	A port Fall Time	-			30	nS
t <sub>EN</sub>	Enable Time	-			200	nS
t <sub>DIS</sub>	Disable Time	-			200	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-			8	nS
t <sub>PLH-A-B</sub>	(Driving A)	-			11	nS
$t_{\rm PHL-B-A}$	Propagation Delay	-			8	nS
t <sub>PLH-B-A</sub>	(Driving B)	-			10	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps

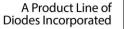
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Continuously. Symbol	Parameter	Test Conditions	Min Typ	Max	Unit
$V_{CCA} = 1.8V \pm 0.15V$ , V	$V_{\rm CCB} = 1.2 \mathrm{V} \pm 0.1 \mathrm{V}$				
t <sub>RB</sub>	B port Rise Time	-		25	nS
t <sub>FB</sub>	B port Fall Time	-		25	nS
t <sub>RA</sub>	A port Rise Time	-		14	nS
t <sub>FA</sub>	A port Fall Time	-		25	nS
t <sub>EN</sub>	Enable Time	-		200	nS
t <sub>DIS</sub>	Disable Time	-		200	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		10	nS
t <sub>PLH-A-B</sub>	(Driving A)	-		15	nS
t <sub>PHL-B-A</sub>	Propagation Delay	-		12	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		12	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		20	Mbps
$V_{CCA} = 1.8V \pm 0.15V$ ,	$V_{CCR} = 2.5V \pm 0.2V$				
t <sub>RB</sub>	B port Rise Time	-		8	nS
t <sub>FB</sub>	B port Fall Time	-		8	nS
t <sub>RA</sub>	A port Rise Time	-		6	nS
t <sub>FA</sub>	A port Fall Time	-		12	nS
t <sub>EN</sub>	Enable Time	-		200	nS
t <sub>DIS</sub>	Disable Time	-		150	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		5	nS
t <sub>PLH-A-B</sub>	(Driving A)	-		4	nS
t <sub>PHL-B-A</sub>	Propagation Delay	-		4	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		4	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		24	Mbp
$V_{CCA} = 1.8V \pm 0.15V$ ,	$V_{CCR} = 3.3V \pm 0.3V$				1 1
t <sub>RB</sub>	B port Rise Time	-		8	nS
t <sub>FB</sub>	B port Fall Time	-		8	nS
t <sub>RA</sub>	A port Rise Time	-		4	nS
t <sub>FA</sub>	A port Fall Time	-		10	nS
t <sub>EN</sub>	Enable Time	-		180	nS
t <sub>DIS</sub>	Disable Time	-		120	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		6	nS
t <sub>PLH-A-B</sub>	(Driving A)	-		4	nS
t <sub>PHL-B-A</sub>	Propagation Delay	-		4	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		4	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		24	Mbp

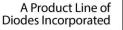






Symbol	Parameter	Test Conditions	Min Typ	Max	Unit
$V_{\rm CCA} = 2.5 \rm V \pm 0.2 \rm V$ ,	$V_{CCB} = 1.2V \pm 0.1V$				
t <sub>RB</sub>	B port Rise Time	-		25	nS
t <sub>FB</sub>	B port Fall Time	-		30	nS
t <sub>RA</sub>	A port Rise Time	-		12	nS
t <sub>FA</sub>	A port Fall Time	-		30	nS
t <sub>EN</sub>	Enable Time	-		200	nS
t <sub>DIS</sub>	Disable Time	-		180	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		10	nS
t <sub>PLH-A-B</sub>	(Driving A)	-		14	nS
t <sub>PHL-B-A</sub>	Propagation Delay	-		20	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		12	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		20	Mbps
$V_{\rm CCA} = 2.5 \rm V \pm 0.2 \rm V, V$	$V_{\rm CCB} = 1.8 \rm V \pm 0.15 \rm V$		•		
t <sub>RB</sub>	B port Rise Time	-		8	nS
t <sub>FB</sub>	B port Fall Time	-		9	nS
t <sub>RA</sub>	A port Rise Time	-		9	nS
t <sub>FA</sub>	A port Fall Time	-		9	nS
t <sub>EN</sub>	Enable Time	-		200	nS
t <sub>DIS</sub>	Disable Time	-		120	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		3	nS
t <sub>PLH-A-B</sub>	(Driving A)	-		2	nS
t <sub>PHL-B-A</sub>	Propagation Delay	-		5	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		5	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		24	Mbp
$V_{CCA} = 2.5V \pm 0.2V,$	$V_{CCB} = 3.3V \pm 0.3V$				
t <sub>RB</sub>	B port Rise Time	-		7	nS
t <sub>FB</sub>	B port Fall Time	-		8	nS
t <sub>RA</sub>	A port Rise Time	-		4	nS
t <sub>FA</sub>	A port Fall Time	-		10	nS
t <sub>EN</sub>	Enable Time	-		200	nS
t <sub>DIS</sub>	Disable Time	-		120	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		3	nS
t <sub>PLH-A-B</sub>	(Driving A)	-		5	nS
$t_{\rm PHL-B-A}$	Propagation Delay	-		4	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		4	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		24	Mbr







Continuously. Symbol	Parameter	Test Conditions	Min Typ	Max	Unit
$V_{CCA} = 3.3V \pm 0.3V$ , V	$V_{CCB} = 1.2V \pm 0.1V$				
t <sub>RB</sub>	B port Rise Time	-		26	nS
t <sub>FB</sub>	B port Fall Time	-		32	nS
t <sub>RA</sub>	A port Rise Time	-		12	nS
t <sub>FA</sub>	A port Fall Time	-		40	nS
t <sub>EN</sub>	Enable Time	-		120	nS
t <sub>DIS</sub>	Disable Time	-		300	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		10	nS
t <sub>PLH-A-B</sub>	(Driving A)	-		14	nS
t <sub>PHL-B-A</sub>	Propagation Delay	-		25	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		12	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		20	Mbps
$V_{\rm CCA} = 3.3V \pm 0.3V, V$	$V_{\rm CCR} = 1.8 \rm V \pm 0.15 \rm V$				
t <sub>RB</sub>	B port Rise Time	-		6	nS
t <sub>FB</sub>	B port Fall Time	-		11	nS
t <sub>RA</sub>	A port Rise Time	-		6	nS
t <sub>FA</sub>	A port Fall Time	-		7	nS
t <sub>EN</sub>	Enable Time	-		120	nS
t <sub>DIS</sub>	Disable Time	-		200	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		4	nS
t <sub>PLH-A-B</sub>	(Driving A)	-		4	nS
t <sub>PHL-B-A</sub>	Propagation Delay	-		5	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		5	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		24	Mbp
$V_{CCA} = 3.3V \pm 0.3V$ ,	$V_{CCB} = 2.5 V \pm 0.2 V$				
t <sub>RB</sub>	B port Rise Time	-		6	nS
t <sub>FB</sub>	B port Fall Time	-		10	nS
t <sub>RA</sub>	A port Rise Time	-		6	nS
t <sub>FA</sub>	A port Fall Time	-		7	nS
t <sub>EN</sub>	Enable Time	-		120	nS
t <sub>DIS</sub>	Disable Time	-		200	nS
t <sub>PHL-A-B</sub>	Propagation Delay	-		4	nS
$t_{PLH-A-B}$	(Driving A)	-		4	nS
t <sub>PHL-B-A</sub>	Propagation Delay	-		4	nS
t <sub>PLH-B-A</sub>	(Driving B)	-		4	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-		1	nS
MDR	Maximum Data Rate	-		24	Mbp





### Timing Characteristics – Open Drain Driving Configuration

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
t <sub>RB</sub>	B port Rise Time	-	-	-	300	nS
t <sub>FB</sub>	B port Fall Time	-	-	-	30	nS
t <sub>RA</sub>	A port Rise Time	-	-	-	300	nS
t <sub>FA</sub>	A port Fall Time	-	-	-	30	nS
t <sub>PHL-A-B</sub>	Propagation Delay (Driving A)	-	-	-	20	nS
t <sub>PLH-A-B</sub>	(Driving A)	-	-	-	260	nS
t <sub>PHL-B-A</sub>	Propagation Delay (Driving B)	-	-	-	20	nS
t <sub>PLH-B-A</sub>	(Driving B)	-	-	-	260	nS
t <sub>PPSKEW</sub>	Part-to-Part Skew	-	-	-	1	nS
MDR	Maximum Data Rate	-	2	-	-	Mbps

## **Test Circuits**

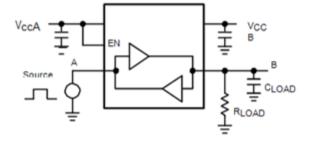


Figure 2.Rail-to-Rail Driving A

Figure 3. Rail-to-Rail Driving B

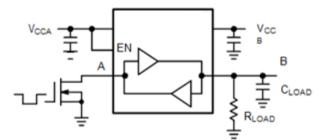


Figure 4. Open-Drain Driving A

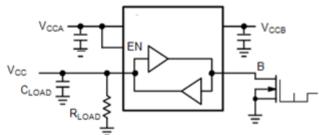


Figure 5. Open-Drain Driving B

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PI4ULS3V204

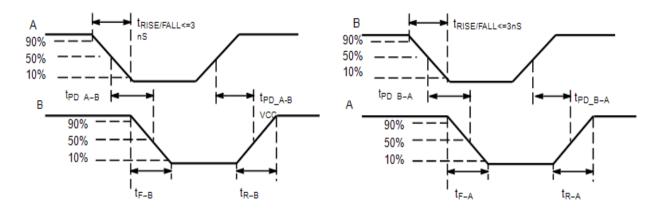
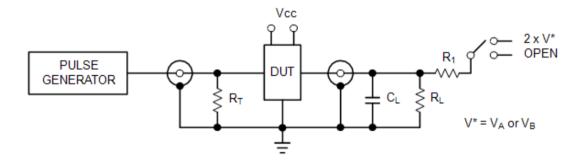


Figure 6. Definition of Timing Specification Parameters



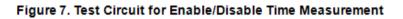
÷	Test	Switch
	t <sub>PZH</sub> , t <sub>PHZ</sub>	Open
	t <sub>PZL</sub> , t <sub>PLZ</sub>	2 x V*

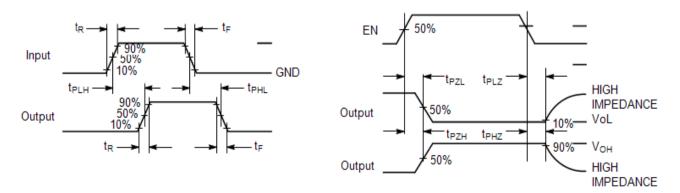
CL = 15 pF or equivalent (Includes jig and probe capacitance)

 $R_L = R_1 = 50 \text{ k} \Omega$  or equivalent

 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ ) V\* = V<sub>A</sub>or V<sub>B</sub> for A or B measurements,

respectively.





#### Figure 8. Timing Definitions for Propagation Delays and Enable/Disable Measurement

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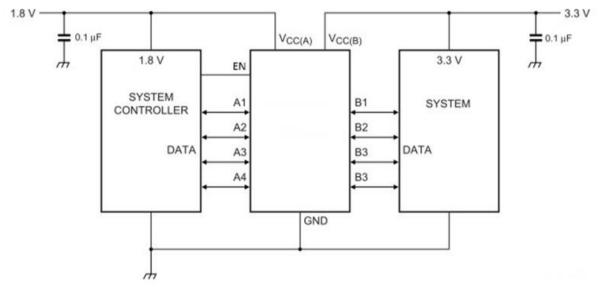


## **Functional Description**

The PI4ULS3V204 is a 4-bit configurable dual-supply bidirectional auto sensing translator that does not require a directional control pin. The A and B ports are designed to track two different power supply rails,  $V_{CCA}$  and  $V_{CCB}$  respectively. Both the  $V_{CCA}$  and  $V_{CCB}$  supply rails are configurable from 1.1 V to 3.6V. This allows voltage logic signals on the  $V_{CCA}$  side to be translated into lower, higher or equal value voltage logic signals on the  $V_{CCB}$  side, and vice-versa.

The translator has integrated 10 k $\Omega$  pull–up resistors on the I/O lines. The integrated pull–up resistors are used to pull–up the I/O lines to either V<sub>CCA</sub> or V<sub>CCB</sub>. The PI4ULS3V204 is an excellent match for open–drain applications such as the I<sup>2</sup>C communication bus.

## **Application Information**



## Level Translator Architecture

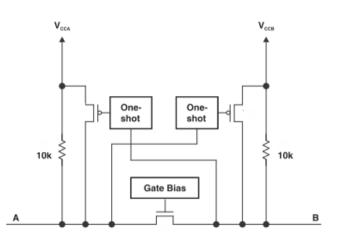
The PI4ULS3V204 auto sense translator provides bidirectional voltage level shifting to transfer data in multiple supply voltage systems. This device has two supply voltages,  $V_{CCA}$  and  $V_{CCB}$ , which set the logic levels on the input and output sides of the translator. When used to transfer data from A port to B port, input signals referenced to the  $V_{CCA}$  supply are translated to output signals with a logic level matched to  $V_{CCB}$ . In a similar manner, translation shifts input signals with a logic level compatible to  $V_{CCB}$  to an output signal matched to  $V_{CCA}$ . The PI4ULS3V204 consists of two bidirectional channels that independently determine the direction of the data flow without requiring a directional pin. The one-shot circuits are used to detect the rising or falling input signals. In addition, the one shots decrease the rise and fall time of the output signal for high-to-low and low-to-high transitions. Each input/output channel has an internal 10 k $\Omega$  pull. The magnitude of the pull-up resistors can be reduced by connecting external resistors in parallel to the internal 10 k $\Omega$  resistors.



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#### **Input Driver Requirements**

The rise ( $t_R$ ) and fall ( $t_F$ ) timing parameters of the open drain outputs depend on the magnitude of the pull-up resistors. In -addition, the propagation times ( $t_{PD}$ ), skew ( $t_{PSKEW}$ ) and maximum data rate depend on the impedance of the device that is connected to the translator. The timing parameters listed in the data sheet assume that the output impedance of the drivers connected to the translator is less than 50 k $\Omega$ .

### **Enable Input (EN)**

The PI4ULS3V204 has an Enable pin (EN) that provides tri-state operation at the I/O pins. Driving the Enable pin to a low logic level minimizes the power consumption of the device and drives the I/O  $V_{CCB}$  and I/O  $V_{CCA}$  pins to a high impedance state. Normal translation operation occurs when the EN pin is equal to a logic high signal. The EN pin is referenced to the  $V_{CCA}$  supply and has overvoltage tolerant protection.

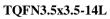
#### **Power Supply Guidelines**

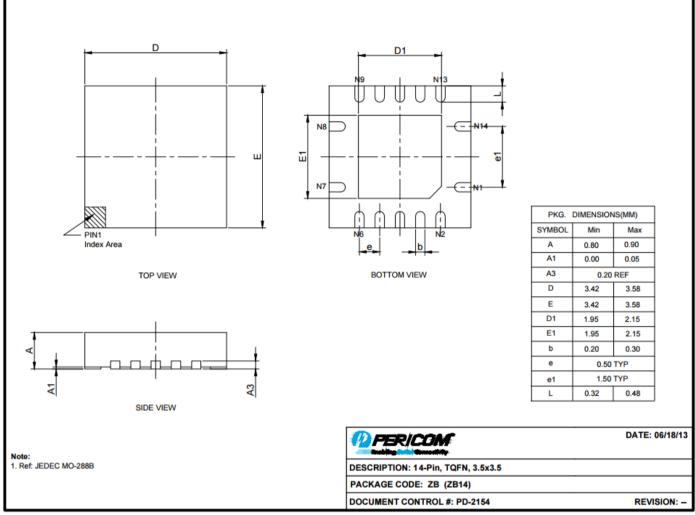
During normal operation, supply voltage  $V_{CCA}$  can be greater than, less than or equal to  $V_{CCB}$ . The sequencing of the power supplies will not damage the device during the power up operation. For optimal performance,  $0.01\mu$ F to  $0.1\mu$ F decoupling capacitors should be used on the  $V_{CCA}$  and  $V_{CCB}$  power supply pins. Ceramic capacitors are a good design choice to filter and bypass any noise signals on the voltage lines to the ground plane of the PCB. The noise immunity will be maximized by placing the capacitors as close as possible to the supply and ground pins, along with minimizing the PCB connection traces.





# **Mechanical Information**





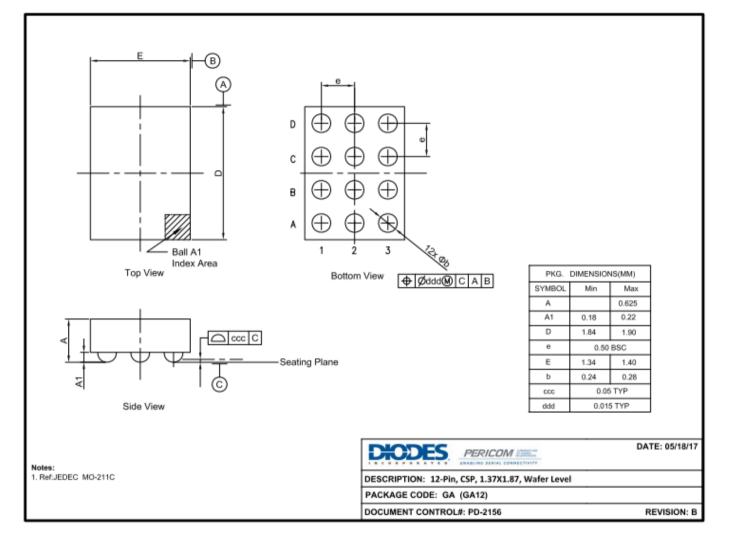
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# **Mechanical Information**

CSP1.37x1.87-12 (GA)

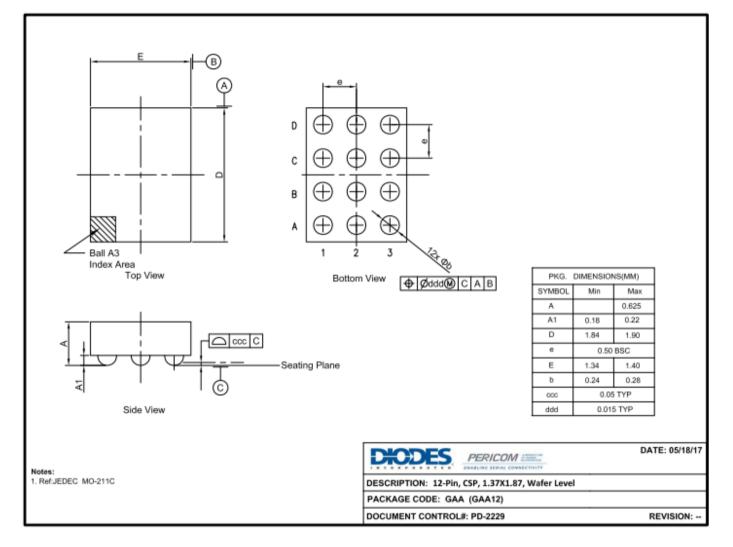






# **Mechanical Information**

CSP1.37x1.87-12 (GAA)



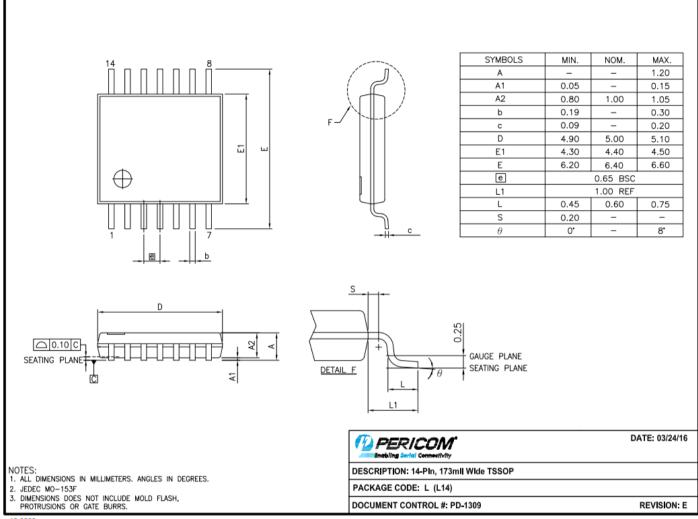


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PI4ULS3V204

## TSSOP-14(L)



#### 16-0060

## **Ordering Information**

Part No.	Package Code	Package
PI4ULS3V204LE	L	14-Pin,173 mil Wide TSSOP
PI4ULS3V204LEX	L	14-Pin,173 mil Wide TSSOP, Tape & reel
PI4ULS3V204ZBEX	ZB	Lead free and Green 14-pin TQFN3.5x3.5, Tape & Reel
PI4ULS3V204GAEX	GA	Lead free and Green 12-pin CSP1.37x1.87, Tape & Reel
PI4ULS3V204GAAEX	GAA	Lead free and Green 12-pin CSP1.37x1.87, Tape & Reel

Note:

- E = Pb-free and Green
- Adding X Suffix= Tape/Reel





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